DATA SHEET (Tentative)

| Part No. | AN26031A |
|------------------|-------------------|
| Package Code No. | ALGA005-W-0609ANA |

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AN26031A (Tentative) Single Band LNA-IC for 2.5 GHz Band Applications

Overview

- AN26031A is a single band LNA (Low Noise Amplifier)-IC for 2.5 GHz Band applications.
- Realizing high performance by using 0.18 μ m SiGeC Bi-CMOS process ($f_T = 90$ GHz, $f_{max} = 140$ GHz).

+3.0 V typ.

- High/Low Gain-mode is changeable, controlled by integrated CMOS logic circuit.
- Achieving miniaturization by using small size Wafer Level Chip Size Package (WLCSP).

Features

Low voltage operation

| e i | 51 | |
|---|---------------|------------------|
| Low current consumption | 7.5 mA typ. | (High-Gain mode) |
| | 7.5 μA typ. | (Low-Gain mode) |
| • High gain | 18.5 dB typ. | (High-Gain mode) |
| • Low noise figure | 0.8 dB typ. | (High-Gain mode) |
| •Low distortion | +2.5 dBm typ. | (High-Gain mode) |

•Small package

Applications

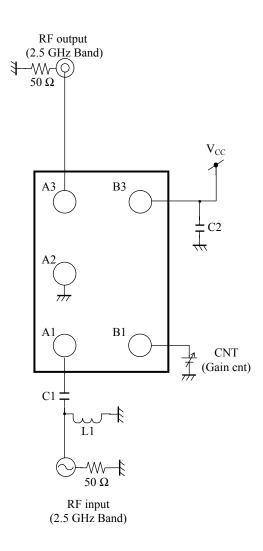
• 2.5 GHz Single Band LNA

Package

- 5 pin Wafer level chip size package (WLCSP) Size : 0.86 × 0.56 mm² (0.3 mm pitch)
- Туре
 - Bi-CMOS IC

- Application Circuit Example (Block Diagram)
 - 2.5 GHz Band Application

(Top View)

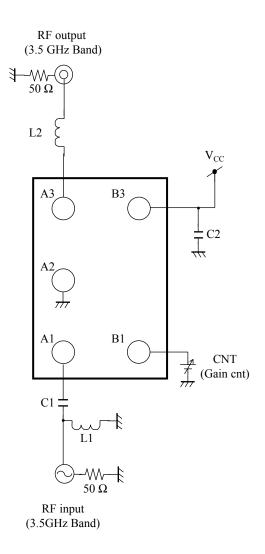


Notes) • This application circuit is an example. The operation of mass production set is not guaranteed. Perform enough evaluation and verification on the design of mass production set.

• This block diagram is for explaining functions. The part of the block diagram may be omitted, or it may be simplified.

- Application Circuit Example (Block Diagram) (continued)
 - 3.5 GHz Band Application

(Top View)



Notes) • This application circuit is an example. The operation of mass production set is not guaranteed. Perform enough evaluation and verification on the design of mass production set.

• This block diagram is for explaining functions. The part of the block diagram may be omitted, or it may be simplified.

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Descriptions

| Pin No. | Pin name | Туре | Description |
|---------|----------|--------------|---------------------------|
| A1 | IN | Input | RF input |
| A2 | GND | Ground | GND |
| A3 | OUT | Output | RF output |
| B1 | CNT | Input | High-Gain/Low-Gain switch |
| B3 | VCC | Power Supply | V _{CC} |

Absolute Maximum Ratings

Note) Absolute maximum ratings are limit values which do not result in damages to this IC, and IC operation is not guaranteed at these limit values.

| A No. | Parameter | Symbol | Rating | Unit | Notes |
|-------|-------------------------------|------------------|-------------|------|-------|
| 1 | Supply voltage | V _{CC} | 3.7 | V | *1 |
| 2 | Supply current | I _{CC} | 18 | mA | — |
| 3 | Power dissipation | P _D | 29 | mW | *2 |
| 4 | Operating ambient temperature | T _{opr} | -40 to +85 | °C | *3 |
| 5 | Storage temperature | T _{stg} | -55 to +125 | °C | *3 |

Notes) *1 :The values under the condition not exceeding the above absolute maximum ratings and the power dissipation.

*2 : The power dissipation shown is the value at $T_a = 75^{\circ}C$ for the independent (unmounted) IC package with a heat sink. When using this IC, refer to the $P_D^{-}T_a$ diagram of the package standard and design the heat radiation with sufficient margin so that the allowable value might not be exceeded based on the conditions of power supply voltage, load, and ambient temperature.

*3 : Except for the power dissipation, operating ambient temperature, and storage temperature, all ratings are for $T_a = 25^{\circ}C$.

Operating supply voltage range

| Parameter | Symbol | Range | Unit | Notes |
|----------------------|-----------------|------------|------|-------|
| Supply voltage range | V _{CC} | 2.7 to 3.6 | V | * |

Note) *: The values under the condition not exceeding the above absolute maximum ratings and the power dissipation.

Allowable Voltage Range

- Notes) Allowable current and voltage ranges are limit ranges which do not result in damages to this IC, and IC operation is not guaranteed within these limit ranges.
 - Voltage values, unless otherwise specified, are with respect to GND.
 - Do not apply external currents or voltages to any pin not specifically mentioned.
 - For the circuit currents, "+" denotes current flowing into the IC, and "-" denotes current flowing out of the IC.

| Pin No. | Pin name | Rating | Unit | Note |
|---------|----------|-------------------------|------|------|
| A1 | IN | — | V | *1 |
| A3 | OUT | -0.3 to V _{CC} | V | _ |
| B1 | CNT | -0.3 to V _{CC} | V | _ |

Note) *1 : RF signal input pin. Do not apply DC current. Do not apply more than 0 dBm to RF input.

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Electrical Characteristics at V_{CC} = 3.0 V

Note) $T_a = 25^{\circ}C \pm 2^{\circ}C$ unless otherwise specified.

| B No. | Parameter | Symbol | Conditions | Limits | | | Unit | Note |
|---------|--------------------------------|-------------------|---|--------|-----|-----|------|------|
| B NO. | i didinotoi | Cymbol | Conditionio | Min | Тур | Max | | Note |
| DC elec | DC electrical characteristics | | | | | | | |
| DC-1 | Supply current HG | I _{CC} H | V_{CC} current at High-Gain mode No input signal | | 7.5 | 10 | mA | |
| DC-2 | Supply current LG | I _{CC} L | V _{CC} current at Low-Gain mode No input signal | | 7.5 | 15 | μΑ | |
| DC-3 | Input voltage (High-Gain mode) | VIH | _ | 1.48 | _ | 3.6 | V | Ι |
| DC-4 | Input voltage (Low-Gain mode) | VIL | _ | 0 | _ | 0.6 | V | |
| DC-5 | SW current (High) | IIH | Current at CNT pin VIH = V _{CC} | _ | 19 | 30 | μA | _ |

\blacksquare Electrical Characteristics (continued) at V_{CC} = 3.0 V

Note) $T_a = 25^{\circ}C \pm 2^{\circ}C$, fRX = 2.5 GHz, PRX = -30 dBm, CW unless otherwise specified.

| B No. | Parameter | Symbol | Conditions | Limits | | | Unit | Note |
|---------|---------------------------|---------|--|--------|------|------|------|------|
| | | | | Min | Тур | Max | | - |
| AC elec | ctrical characteristics | | | | | | | |
| A-1 | Power Gain HG | GHS | High-Gain mode | 16.6 | 18.5 | 20 | dB | — |
| A-2 | Power Gain LG | GLS | Low-Gain mode | -8.8 | -7 | -5.2 | dB | _ |
| A-3 | IIP3 –10 MHz offset HG | IIP3H1S | High-Gain mode f1 = fRX - 10 MHz f2 = fRX - 20 MHz Input 2 signals (f1, f2) | -2 | 2.5 | | dBm | |

Electrical Characteristics (Reference values for design) at V_{CC} = 3.0 V

 Notes) T_a = 25°C±2°C, fRX = 2.3 GHz, 2.5 GHz, 2.7 GHz, PRX = -30 dBm, CW unless otherwise specified. The characteristics listed below are reference values derived from the design of the IC and are not guaranteed by inspection. If a problem does occur related to these characteristics, we will respond in good faith to user concerns.

| B No. | Deremeter | Symbol | Conditions | Reference values | | | Unit | Note |
|---------|----------------------------|---------|---|------------------|------|------|------|------|
| D INU. | Parameter | Symbol | Conditions | Min | Тур | Max | Unit | note |
| AC elec | trical characteristics | | | | | | | |
| C-1 | Power Gain HG | GHa | High-Gain mode | 16.1 | 18.5 | 20.5 | dB | — |
| C-2 | Power Gain LG | GLa | Low-Gain mode PRX = -20 dBm | -9 | -7 | -5 | dB | _ |
| C-3 | Noise Figure HG | NFHa | High-Gain mode | _ | 0.95 | 1.45 | dB | *1 |
| C-4 | Noise Figure LG | NFLa | Low-Gain mode | _ | 7 | 9.5 | dB | *1 |
| C-5 | IIP3 –10 MHz offset HG | IIP3H1a | $IIP3H1a \begin{array}{c} High-Gain mode \\ f1 = fRXa - 10 MHz \\ f2 = fRXa - 20 MHz \\ Input 2 signals (f1, f2) \end{array}$ | | 2.5 | | dBm | |
| C-6 | IIP3 +10 MHz offset HG | IIP3H2a | IIP3H2a High-Gain mode f1 = fRXa + 10 MHz f2 = fRXa + 20 MHz Input 2 signals (f1, f2) | | 2.0 | _ | dBm | _ |
| C-7 | Input P1dB HG | IP1dBHa | 1dBHa High-Gain mode | | -8.5 | _ | dBm | |
| C-8 | IIP3 +100 kHz offset LG | IIP3La | 3La Low-Gain mode f1 = fRXa f2 = fRXa + 100 kHz Input 2 signals (f1, f2) | | 24.5 | _ | dBm | |
| C-9 | Input P1dB LG | IP1dBLa | Low-Gain mode | 0 | 8 | — | dBm | — |
| C-10 | Reverse Isolation HG | ISOHa | High-Gain mode | 26 | 31 | _ | dB | |
| C-11 | Reverse Isolation LG | ISOLa | Low-Gain mode | 4.5 | 7 | — | dB | _ |
| C-12 | Input Return Loss HG | S11Ha | High-Gain mode | 10 | 16 | | dB | |
| C-13 | Input Return Loss LG | S11La | Low-Gain mode | 7 | 8.5 | _ | dB | |
| C-14 | Output Return Loss HG | S22Ha | High-Gain mode | 10 | 19 | _ | dB | |
| C-15 | Output Return Loss LG | S22La | Low-Gain mode | 9.5 | 14.5 | | dB | _ |

Note) *1 : Connector & substrate loss (0.14 dB) included.

Control Pin Mode Table

Note) See parameters B No. DC-3 / B No. DC-4 in the Electrical Characteristics for control voltage retention ranges.

| Pin No. | Description | Pin vo | oltage | Remarks |
|---------|---|----------|-----------|---------|
| PIN NO. | Description | Low | High | Remarks |
| B1 | High-Gain/Low-Gain Switching (Gain Control) | Low-Gain | High-Gain | _ |

Truth Table

Note) See parameters B No. DC-3 / B No. DC-4 in the Electrical Characteristics for control voltage retention ranges.

| CNT | LNA | Mode |
|------|-----------|-----------|
| High | High-Gain | High-Gain |
| Low | Low-Gain | Low-Gain |

Technical Data

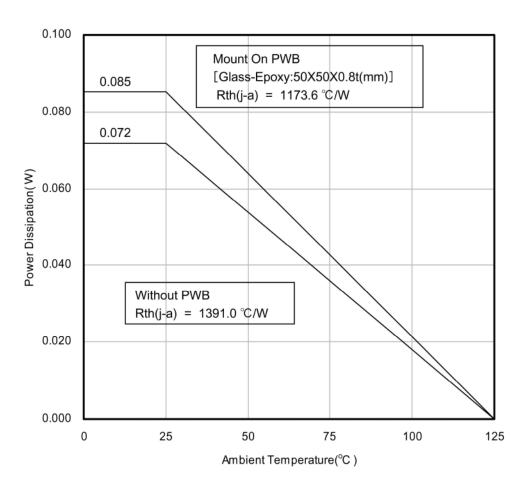
I/O block circuit diagram and pin function descriptions

Note) The characteristics listed below are reference values derived from the design of the IC and are not guaranteed.

| Pin No. | Waveform and voltage | Internal circuit | Impedance | Description |
|------------|----------------------|---|-----------|--|
| Al | 0.8 V | V _{cc} | | LNA input |
| A2 | 0.0 V | _ | _ | GND |
| A3 | | V _{cc} A GND | | LNA output |
| B1 | _ | (BI) (BI) (BI) (BI) (BI) (BI) (BI) (BI) | 160 kΩ | High-Gain/Low-Gain SW input Less than 0.60 V : Low-Gain mode More than 1.48 V : High-Gain mode |
| В3 | 3.3 V | (B3) GND | _ | Voltage supply |

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- Technical Data (continued)
- $P_D T_a$ diagram



Usage Notes

- Special attention and precaution in using
 - 1. This IC is intended to be used for general electronic equipment [2.5 GHz Band Applications].
 - Consult our sales staff in advance for information on the following applications:
 - Special applications in which exceptional quality and reliability are required, or if the failure or malfunction of this IC may directly jeopardize life or harm the human body.
 - Any applications other than the standard applications intended.
 - (1) Space appliance (such as artificial satellite, and rocket)
 - (2) Traffic control equipment (such as for automobile, airplane, train, and ship)
 - (3) Medical equipment for life support
 - (4) Submarine transponder
 - (5) Control equipment for power plant
 - (6) Disaster prevention and security device
 - (7) Weapon
 - (8) Others : Applications of which reliability equivalent to (1) to (7) is required

It is to be understood that our company shall not be held responsible for any damage incurred as a result of or in connection with your using the IC described in this book for any special application, unless our company agrees to your using the IC in this book for any special application.

- 2. Pay attention to the direction of LSI. When mounting it in the wrong direction onto the PCB (printed-circuit-board), it might smoke or ignite.
- 3. Pay attention in the PCB (printed-circuit-board) pattern layout in order to prevent damage due to short circuit between pins. In addition, refer to the Pin Description for the pin configuration.
- 4. Perform a visual inspection on the PCB before applying power, otherwise damage might happen due to problems such as a solderbridge between the pins of the semiconductor device. Also, perform a full technical verification on the assembly quality, because the same damage possibly can happen due to conductive substances, such as solder ball, that adhere to the LSI during transportation.
- 5. Take notice in the use of this product that it might break or occasionally smoke when an abnormal state occurs such as output pin-VCC short (Power supply fault), output pin-GND short (Ground fault), or output-to-output-pin short (load short). And, safety measures such as an installation of fuses are recommended because the extent of the above-mentioned damage and smoke emission will depend on the current capability of the power supply.
- 6. When designing your equipment, comply with the range of absolute maximum rating and the guaranteed operating conditions (operating power supply voltage and operating environment etc.). Especially, please be careful not to exceed the range of absolute maximum rating on the transient state, such as power-on, power-off and mode-switching. Otherwise, we will not be liable for any defect which may arise later in your equipment.
 Even when the products are used within the guaranteed values, take into the consideration of incidence of break down and failure.

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- 7. When using the LSI for new models, verify the safety including the long-term reliability for each product.
- 8. When the application system is designed by using this LSI, be sure to confirm notes in this book. Be sure to read the notes to descriptions and the usage notes in the book.
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